### **VS-20CUT10, VS-20CWT10FN**

Vishay Semiconductors

COMPLIANT

## High Performance Schottky Generation 5.0, 2 x 10 A





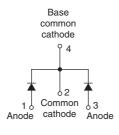
I-PAK(TO-251AA) D-PAK(TO-252AA)

Base common cathode

4

1 3

Anode Common cathode



VS-20CUT10

VS-20CWT10FN

PRODUCT SUMMARY				
Doolsome	D-PAK (TO-252AA),			
Package	I-PAK (TO-251AA)			
I <sub>F(AV)</sub>	2 x 10 A			
$V_{R}$	100 V			
V <sub>F</sub> at I <sub>F</sub>	0.66 V			
I <sub>RM</sub> max.	4 mA at 125 °C			
T <sub>J</sub> max.	175 °C			
Diode variation	Common cathode			
E <sub>AS</sub>	54 mJ			

#### **FEATURES**

- 175 °C high performance Schottky diode
- Very low forward voltage drop
- Extremely low reverse leakage
- Optimized V<sub>F</sub> vs. I<sub>R</sub> trade off for high efficiency
- Increased ruggedness for reverse avalanche capability
- RBSOA available
- Negligible switching losses
- Submicron trench technology
- Compliant to RoHS Directive 2002/95/EC

#### **APPLICATIONS**

- High efficiency SMPS
- High frequency switching
- · Output rectification
- Reverse battery protection
- Freewheeling
- DC/DC systems
- Increased power density systems

MAJOR RATINGS AND CHARACTERISTICS						
SYMBOL	CHARACTERISTICS VALUES UNITS					
$V_{RRM}$		100	V			
V <sub>F</sub>	10 Apk, T <sub>J</sub> = 125 °C (typical, per leg)	0.615	V			
TJ	Range	- 55 to 175	°C			

VOLTAGE RATINGS				
PARAMETER	SYMBOL	TEST CONDITIONS	VS-20CUT10 VS-20CWT10FN	UNITS
Maximum DC reverse voltage	$V_{R}$	T <sub>J</sub> = 25 °C	100	V



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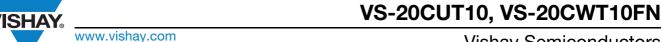
ABSOLUTE MAXIMUM RATINGS						
PARAMETER		SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average	per leg		50 % duty cycle at T <sub>C</sub> = 159 °C, rectangular waveform		10	А
forward current	per device	I <sub>F(AV)</sub>			20	
Maximum peak one c	ycle	I <sub>FSM</sub>	5 μs sine or 3 μs rect. pulse Following any rated load condition and with rated		610	А
non-repetitive surge c	non-repetitive surge current per leg		10 ms sine or 6 ms rect. pulse	V <sub>RRM</sub> applied	110	
Non-repetitive avalance energy per leg	che	E <sub>AS</sub>	T <sub>J</sub> = 25 °C, I <sub>AS</sub> = 3 A, L = 12 mH		54	mJ
Repetitive avalanche of	current per leg	I <sub>AR</sub>	Limited by frequency of operation and time pulse duration so that $T_J < T_J max$ . $I_{AS}$ at $T_J max$ . as a function of time pulse (see fig. 8)		I <sub>AS</sub> at T <sub>J</sub> max.	А

ELECTRICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS		TYP.	MAX.	UNITS
Forward voltage drop per leg	V <sub>FM</sub> <sup>(1)</sup>	10 A	- T <sub>J</sub> = 25 °C	0.735	0.810	V
		20 A		0.840	0.890	
		10 A	- T <sub>J</sub> = 125 °C	0.615	0.660	
		20 A		0.730	0.770	
Reverse leakage current per leg	I <sub>RM</sub> <sup>(1)</sup>	T <sub>J</sub> = 25 °C	V <sub>R</sub> = Rated V <sub>R</sub>	-	50	μΑ
		T <sub>J</sub> = 125 °C		-	4	mA
Junction capacitance per leg	C <sub>T</sub>	$V_R = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz), 25 °C		400	-	pF
Series inductance per leg	Ls	Measured lead to lead 5 mm from package body		8.0	-	nH
Maximum voltage rate of change	dV/dt	Rated V <sub>R</sub>		-	10 000	V/µs

#### Note

 $<sup>^{(1)}\,</sup>$  Pulse width < 300  $\mu s,$  duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		- 55 to 175	°C	
Maximum thermal resistance, junction to case per leg	Б	DC operation	2		
Maximum thermal resistance, junction to case per device	- R <sub>thJC</sub>	DC operation	1	°C/W	
Typical thermal resistance, case to heatsink	R <sub>thCS</sub>		0.3		
Approximate weight			0.3	g	
Approximate weight			0.01	OZ.	
Mandan de ter		Case style I-PAK		20CUT10	
Marking device		Case style D-PAK	20CW	T10FN	



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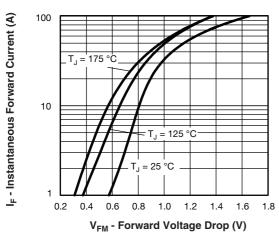


Fig. 1 - Maximum Forward Voltage Drop Characteristics

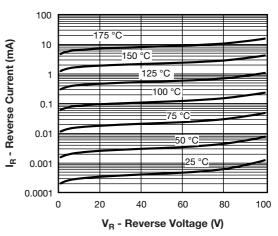


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

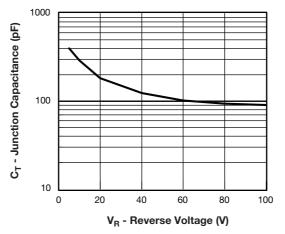


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

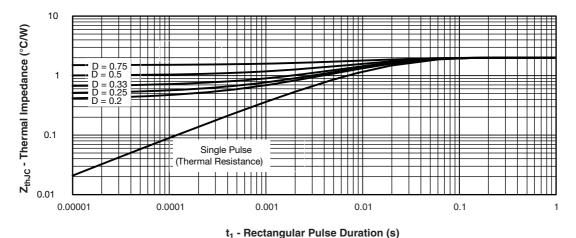
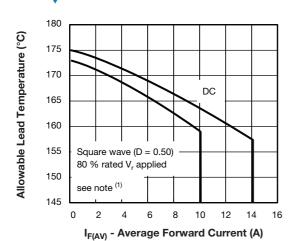


Fig. 4 - Maximum Thermal Impedance Z<sub>thJC</sub> Characteristics



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Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

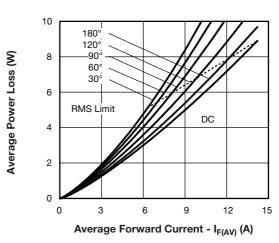


Fig. 6 - Forward Power Loss Characteristics

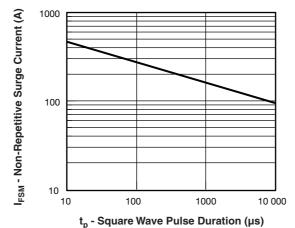


Fig. 7 - Maximum Non-Repetitive Surge Current

#### Note

(1) Formula used:  $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$ ;  $Pd = Forward power loss = I_{F(AV)} \times V_{FM}$  at  $(I_{F(AV)}/D)$  (see fig. 6);  $Pd_{REV} = Inverse power loss = V_{R1} \times I_R (1 - D)$ ;  $I_R$  at  $V_{R1} = 80 \%$  rated  $V_R$ 

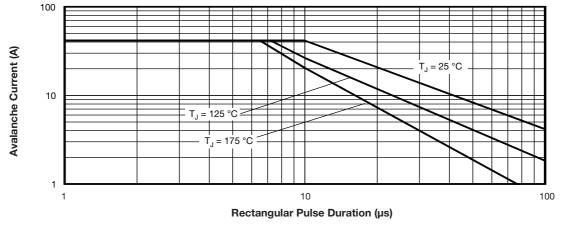


Fig. 8 - Reverse Bias Safe Operating Area (Avalanche Current vs. Rectangular Pulse Duration)

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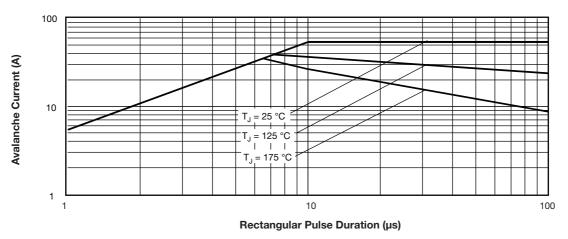
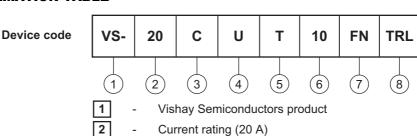


Fig. 9 - Reverse Bias Safe Operating Area (Avalanche Energy vs. Rectangular Pulse Duration)

#### **ORDERING INFORMATION TABLE**



Circuit configuration:
 C = Common authority

C = Common cathode

4 - Package: • U = I-PAK

• W = D-PAK

5 - T = Trench

Voltage rating (10 = 100 V)TO-252AA (D-PAK)

8 - D-PAK, I-PAK:

None = Tube (75 pieces)

D-PAK only:

• TR = Tape and reel

• TRL = Tape and reel (left oriented)

• TRR = Tape and reel (right oriented)

LINKS TO RELATED DOCUMENTS					
Dimensions	I-PAK (TO-251AA)	www.vishay.com/doc?95024			
Dimensions	D-PAK (TO-252AA)	www.vishay.com/doc?95448			
Part marking information	I-PAK (TO-251AA)	www.vishay.com/doc?95025			
	D-PAK (TO-252AA)	www.vishay.com/doc?95059			
Packaging information		www.vishay.com/doc?95033			
SPICE model		www.vishay.com/doc?95041			

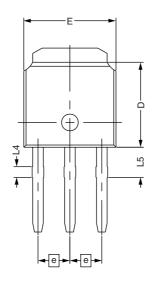
Revision: 02-Nov-11 5 Document Number: 94651

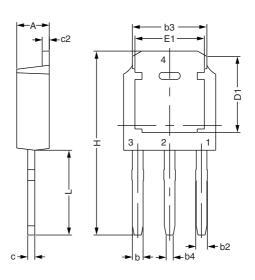


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## I-PAK - S

### **DIMENSIONS FOR I-PAK - S** in millimeters





SYMBOL	DIMENSIONAL REQUIREMENTS				
STWIBOL	MIN.	NOM.	MAX.		
E	6.40	6.60	6.70		
L	3.98	4.13	4.28		
L4	0.66	0.76	0.86		
L5	1.96	2.16	2.36		
D	6.00	6.10	6.20		
Н	11.05	11.25	11.45		
b	0.64	0.76	0.88		
b2	0.77	0.84	1.14		
b3	5.21	5.34	5.46		
b4	0.41	0.51	0.61		
е		2.286 BSC			
Α	2.20	2.30	2.38		
С	0.40	0.50	0.60		
c2	0.40	0.50	0.60		
D1	5.30	-	-		
E1	4.40		-		

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